

INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>				Docket Number (Optional) SEC.1100		Application Number 10/788,407 NEW	
				Applicant(s) Young-nam HWANG et al.		Filing Date MARCH 1, 2004	
U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
(A)	A	6,545,907	04/08/2003	LOWREY et al.			
(A)	B	2003/0002332	01/02/2003	LOWREY			
(A)	C	6,487,113	11/26/2002	PARK et al.			
(A)	D	6,075,719	06/13/2000	LOWREY et al.			
FOREIGN PATENT DOCUMENTS							
REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
(A)						YES	NO
(A)							
(A)							
(A)							
(A)							
(A)							
OTHER DOCUMENTS <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>							
(A)	E	Y.N. Hwang et al., "Completely CMOS-Compatible Phase-Change Nonvolatile RAM Using NMOS Cell Transistors"					
(A)	F	Manzur Gill et al., "Ovonic Unified Memory - A High-Performance Nonvolatile Memory Technology for Stand-Alone Memory and Embedded Applications," ISSCC 2002/Session 12/TD: Digital Directions/12.4, pages 158-159, and 445-446.					
EXAMINER <i>Lee Seoblong</i>				DATE CONSIDERED <i>11/05</i>			
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							

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Application Number *10/788,407*
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Applicant(s)
Young-man HWANG et al.

Filing Date
March 1, 2004

Group Art Unit
2827
TO BE ASSIGNED

*EXAMINER
INITIAL

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

P C Stefan Lai et al., "OUM - A 180 nm Nonvolatile Memory Cell Element Technology For Stand Alone and Embedded Applications," IEDM 01-803 - 806.

P H Y.N. Hwang et al., "Phase-Change Chalcogenide Nonvolatile RAM Completely Based on CMOS Technology"

P I Linda Geppert, "The New Indelible Memories," IEEE Spectrum, March 2003, pages 49-54.

P J Jon Maimon et al., "Chalcogenide-Based Non-Volatile Memory Technology," pages 5-2289 - 5-2294.

EXAMINER

DATE CONSIDERED

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